

SANCOM

SA-PAN020024-P40

2.0-2.4 GHz High Power GaN-HEMT

Features

Frequency Range: 2.0-2.4 GHz

 $P_{\text{sat}} \geq 40 \text{ dBm}$ Power Gain: $\geq 14 \text{ dB}$

Efficiency = 50% (Type)

 $Z_{\text{in}} / Z_{\text{out}} = 50 \Omega$ 

Description

Sancom Electric's GaN-HEMT SA-PAN020024-P40 offers high power, high efficiency, ease of matching and greater consistency for high power applications with 28V operation. The SA-PAN020024-P40 typically provides 40 dBm of saturated output power and 14 dB of large-signal gain and can be widely used in various RF/microwave systems.

ABSOLUTE MAXIMUM RATINGS

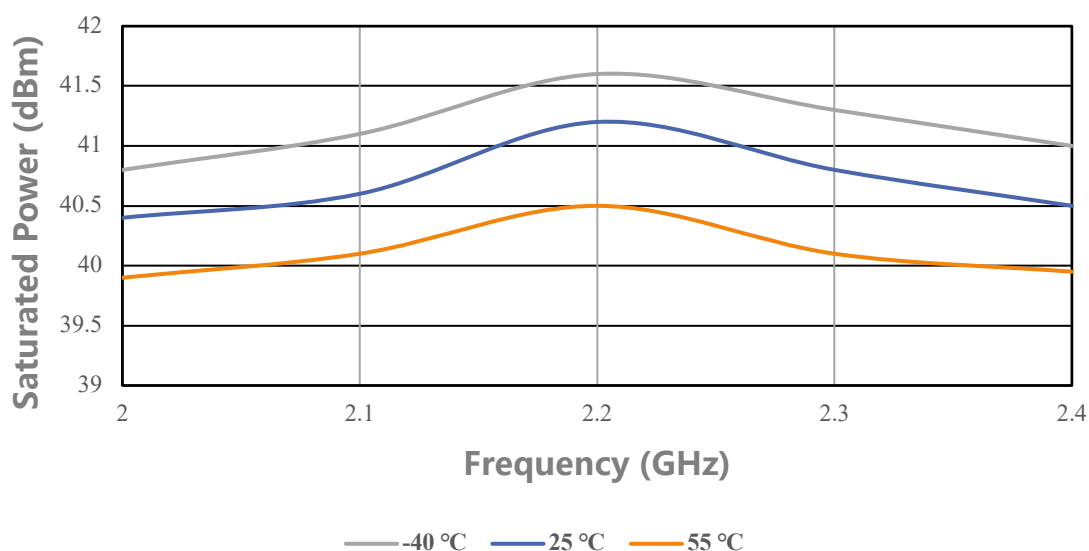
| Parameter | Symbol | Condition | Rating | Unit |
|----------------------|-----------|------------------|------------|-------------|
| Drain-Source Voltage | V_{DS} | $TC=25^{\circ}C$ | 40 | V |
| Gate-Source Voltage | V_{GS} | $TC=25^{\circ}C$ | -5 | V |
| Storage Temperature | T_{stg} | $TC=25^{\circ}C$ | -65 to 150 | $^{\circ}C$ |
| Channel Temperature | T_{ch} | $TC=25^{\circ}C$ | 150 | $^{\circ}C$ |

ELECTRICAL SPECIFICATIONS

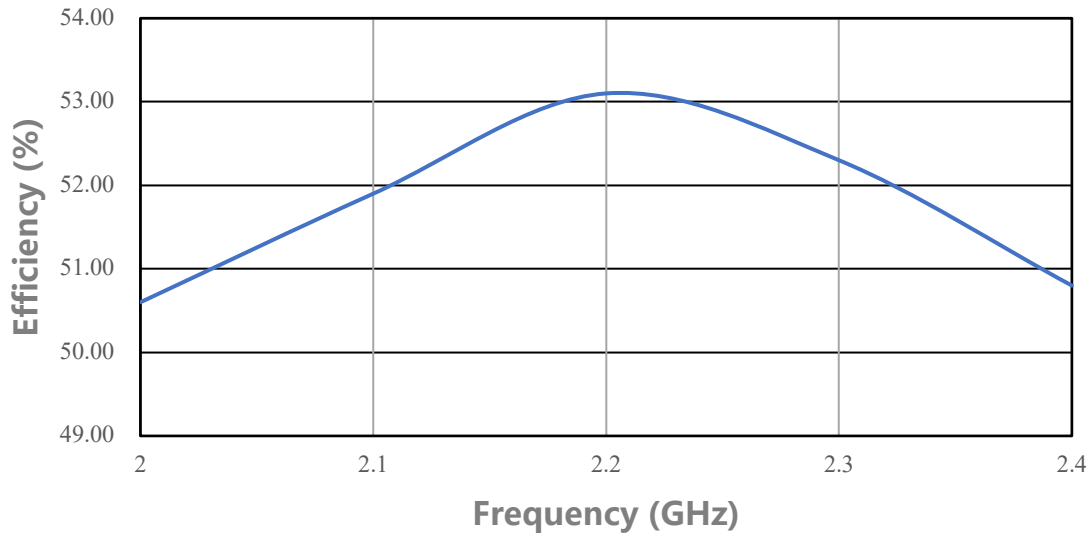
| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|----------------------|------------|---|------|-----|-----|------|
| Drain-Source Current | I_{DS} | $V_{DS}: 28 V$ CW (Continuous Wave) $P_{in}: 26 dBm$ Freq: 2 ~ 2.4 GHz | - | 0.7 | - | A |
| Saturated Power | P_{sat} | | 40 | - | - | dBm |
| Power Gain | G_p | | 14 | - | - | dB |
| Efficiency | η | | - | 50 | - | % |
| Flatness | ΔG | | -0.8 | - | 0.8 | dB |

Performance Plots

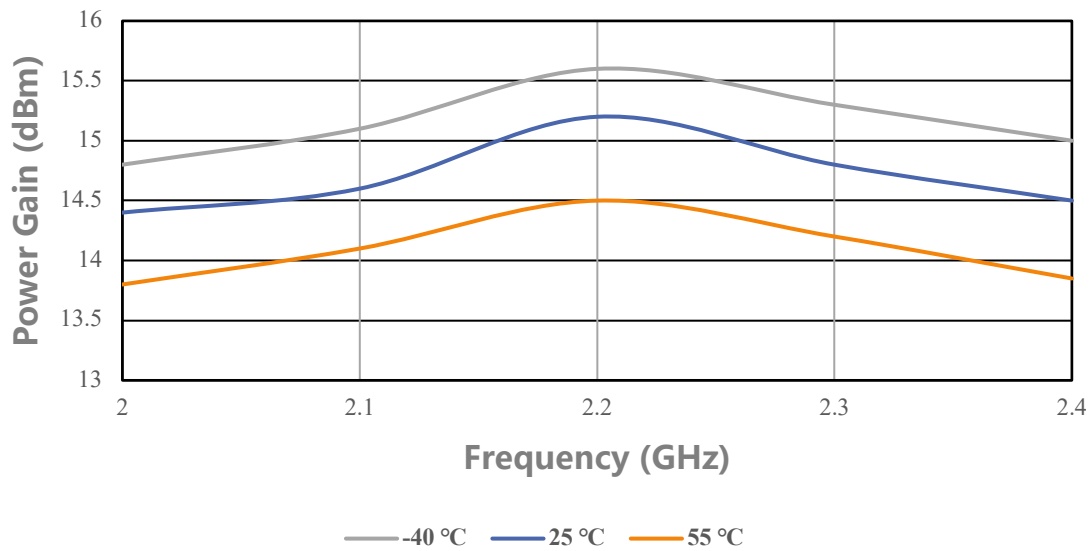
Saturated Power VS Frequency



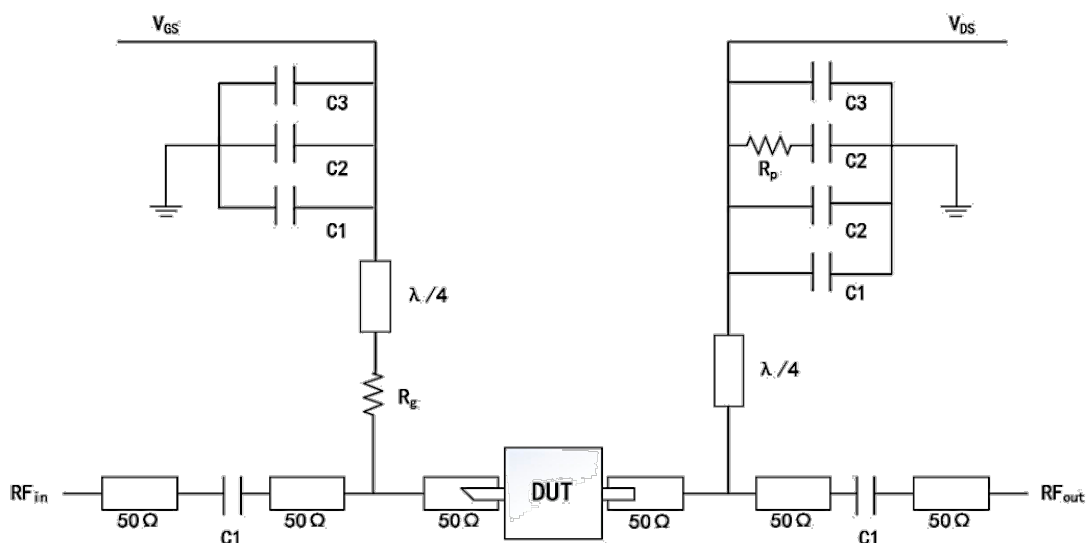
Efficiency VS Frequency



Power Gain VS Frequency



Simplified Block Diagram



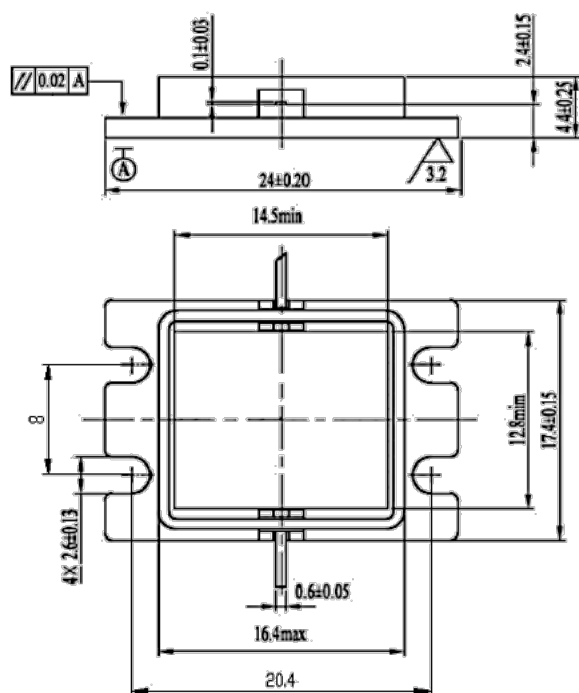
DUT information

| | |
|-----------------|-----------------|
| C1: 8 pF | Rp: 51 Ω |
| C2: 1000 pF | Rg: 15 Ω |
| C3: 100 μ F | |

ESD Protection

| | | |
|-----|-----------|--------|
| ESD | Class III | 2000 V |
|-----|-----------|--------|

Outline Drawing



Unit: mm

Attention

- Please keep away from moisture during transportation and storage
- Pay attention to ESD prevention during chip use and assembly. Wear a grounding ESD bracelet.
- When adding electricity, add gate electricity first and then add leakage electricity